

New Product

Vishay Siliconix

High-Bandwidth, Low Voltage, Dual SPDT Analog Switch

FEATURES

- Single Supply (1.8 V to 5.5 V)
- $\bullet~$ Low On-Resistance $r_{\mbox{ON:}}$ 2.4 Ω
- Crosstalk and Off Isolation: -81 dB @ 1 MHz
- QFN-12 (3 x 3 mm) Package

BENEFITS

- Reduced Power Consumption
- High Accuracy
- Reduce Board Space
- Low-Voltage Logic Compatible
- High Bandwidth

APPLICATIONS

- Cellular Phones
- Speaker Headset Switching
- Audio and Video Signal Routing
- PCMCIA Cards
- Low-Voltage Data Acquisition
- ATE

DESCRIPTION

The DG2032 is a monolithic CMOS dual single-pole/double-throw (SPDT) analog switch. It is specifically designed for low-voltage, high bandwidth applications.

The DG2032's on-resistance (3 Ω @ 2.7 V), matching and flatness are guaranteed over the entire analog voltage range. Wide dynamic performance is achieved with better than $-80~\mathrm{dB}$ for both cross-talk and off-isolation at 1 MHz.

Both SPDT's operate with independent control logic, conduct equally well in both directions and block signals up to the

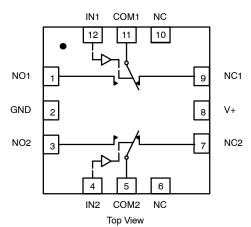
power supply level when off. Break-before-make is guaranteed.

With fast switching speeds, low on-resistance, high bandwidth, and low charge injection, the DG2032 is ideally suited for audio and video switching with high linearity.

Built on Vishay Siliconix's low voltage CMOS technology, the DG2032 contains an epitaxial layer which prevents latch-up.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG2032 12-Pin QFN (3 X 3 mm)



TRUTH TABLE					
Logic NC1 and NC2 NO1 and N					
0	ON	OFF			
1	OFF	ON			

ORDERING INFORMATION					
Temp Range	Package	Part Number			
-40 to 85°C	12-Pin QFN (3 x 3 mm)	DG2032DN			

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ABSOLUTE MAXIMUM RATINGS

Reference to GND	
V+	0.3 to +6 V
IN, COM, NC, NO ^a	
Continuous Current (Any terminal)	±50 mA
Peak Current	± 200 mA
(Pulsed at 1 ms, 10% duty cycle)	
Storage Temperature (D Suffix)	65 to 150°C
Power Dissipation (Packages)b	
12-Pin QFN (3 x 3) ^c	1295 mW
Package Solder Reflow Conditions ^d	
12-Pin QFN (3 x 3)	240°C

Notes:

- otes:
 Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
 All leads welded or soldered to PC Board.
 Derate 16.2 mW/°C above 70°C
 Manual soldering with an iron is not recommended for leadless components. The QFN is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

SPECIFICATIONS (V+	= 3 V)						1
Parameter		Test Conditions Otherwise Unless Specified V+ = 3 V, ±10%, V _{IN} = 0.4 or 2.0 V ^e	Temp ^a	Limits -40 to 85°C			
	Symbol			Minb	Typc	Max ^b	Unit
Analog Switch	·						
Analog Signal Range ^d	V_{NO}, V_{NC}, V_{COM}		Full	0		V+	V
On-Resistance	r _{ON}	$V+ = 2.7 \text{ V}, V_{COM} = 0.2 \text{ V}/1.5 \text{ V}$ $I_{NO}, I_{NC} = 10 \text{ mA}$	Room Full		3.0	5 6.5	Ω
r _{ON} Flatness	r _{ON} Flatness	V+ = 2.7 V V _{COM} = 0 to V+, I _{NO} , I _{NC} = 10 mA	Room			1.6	
r _{ON} Match Between Channels	Δr_{ON}		Room			0.4	
Outline Office and outline of	I _{NO(off)} , I _{NC(off)}	V+ = 3.3 V, V _{NO} , V _{NC} = 0.3 V/3 V	Room Full	-1 -10	0.01	1 10	nA
Switch Oil Leakage Current	I _{COM(off)} VY = 3.3 V, VNC, VNC = 0.3 V/3 V V _{COM} = 3 V/0.3 V		Room Full	-1 -10	0.01	1 10	
Channel-On Leakage Current	I _{COM(on)}	V+ = 3.3 V, V _{NO} , V _{NC} = V _{COM} = 0.3 V/3 V	Room Full	-1 -10	0.01	1 10	
Digital Control							•
Input High Voltage	V _{INH}		Full	2.0			V
Input Low Voltage	V _{INL}		Full			0.4	v
Input Capacitance	C _{in}		Full		5		pF
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	1		1	μΑ
Dynamic Characteristics							•
Turn-On Time	t _{ON}	. V_{NO} or V_{NC} = 2.0 V, R_L = 50 Ω , C_L = 35 pF	Room Full		28	53 59	ns
Turn-Off Time	t _{OFF}		Room Full		13	38 38	
Break-Before-Make Time	t _d	V_{NO} or V_{NC} = 2.0 V, R_L = 50 Ω , C_L = 35 pF	Full	1			1
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		38		pC
Off-Isolation ^d	OIRR	$R_L = 50 \ \Omega, \ C_L = 5 \ pF, \ f = 1 \ MHz$	Room		-78		dB
Crosstalk ^d	X _{TALK}		Room		-82		
N _O , N _C Off Capacitance ^d	C _{NO(off)}	V _{IN} = 0 or V+, f = 1 MHz	Room		15		- pF
	C _{NC(off)}		Room		15		
Channel-On Capacitance ^d	C _{NO(on)}		Room		49		
	C _{NC(on)}		Room		45		
Power Supply							
Power Supply Current	I+	V _{IN} = 0 or V+	Full		0.01	1.0	μΑ

Notes:

- Room = 25° C, Full = as determined by the operating suffix.
- Typical values are for design aid only, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guarantee by design, nor subjected to production test. V_{IN} = input voltage to perform proper function.





0

-60

-40

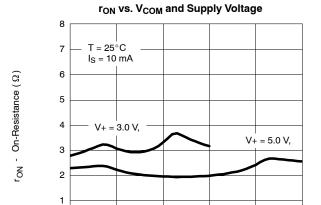
-20

0

0

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

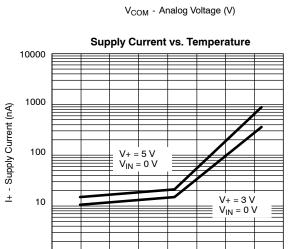
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4

5



Leakage Current vs. Temperature

Temperature (°C)

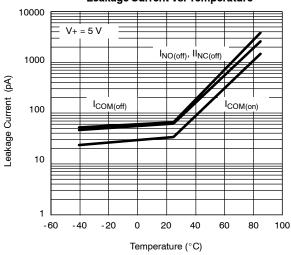
20

40

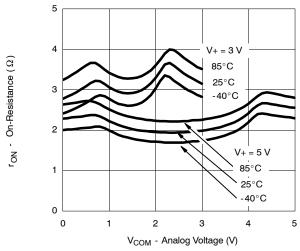
60

80

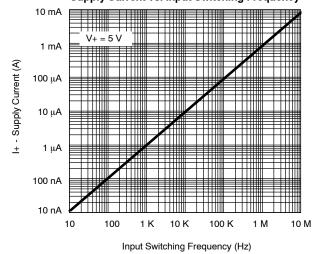
100



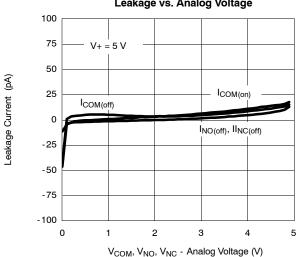
r_{ON} vs. Analog Voltage and Temperature



Supply Current vs. Input Switching Frequency



Leakage vs. Analog Voltage

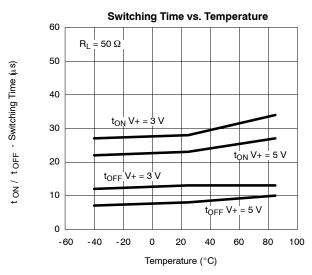


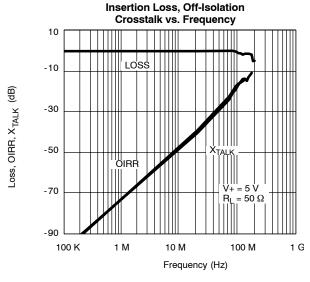
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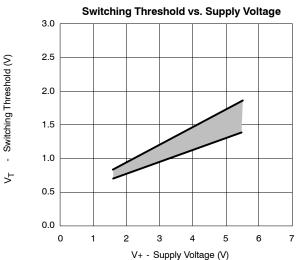
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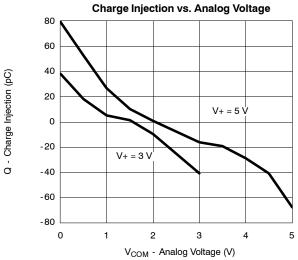


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

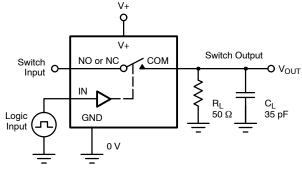








TEST CIRCUITS



V_{INL}

 t_{ON}

 V_{INH}

Logic

Switch

Output

C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

50%

FIGURE 1. Switching Time

 $t_{r} < 5 \text{ ns}$

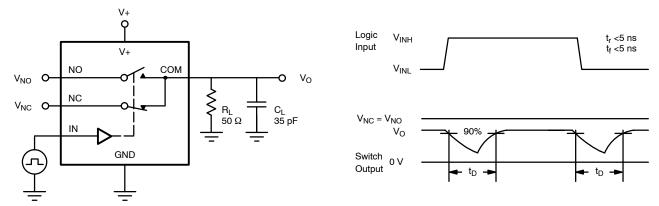
 $t_f < 5 \text{ ns}$

0.9 x V_{OUT}



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TEST CIRCUITS



C_L (includes fixture and stray capacitance)

FIGURE 5. Break-Before-Make Interval

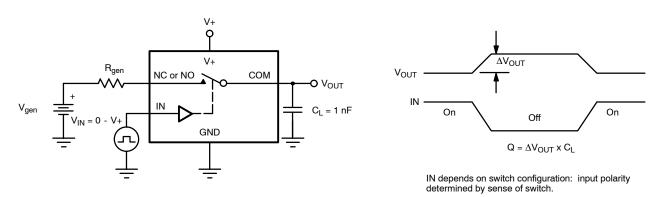


FIGURE 2. Charge Injection

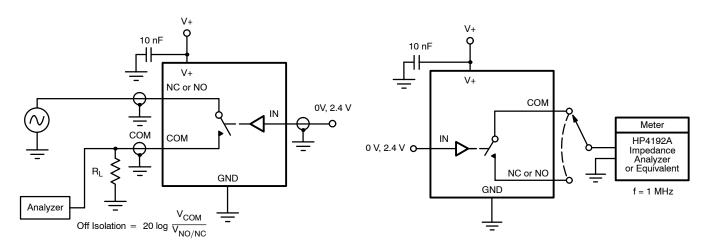


FIGURE 3. Off-Isolation

FIGURE 4. Channel Off/On Capacitance



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